

## High voltage fast-switching NPN power transistor

### Features

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Integrated antiparallel collector-emitter diode

### Application

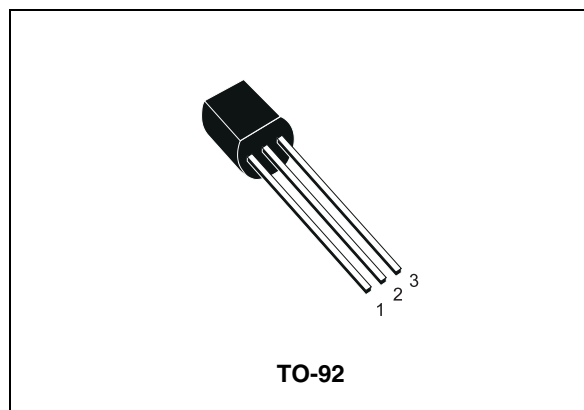
- Electronic ballast for fluorescent lighting

### Description

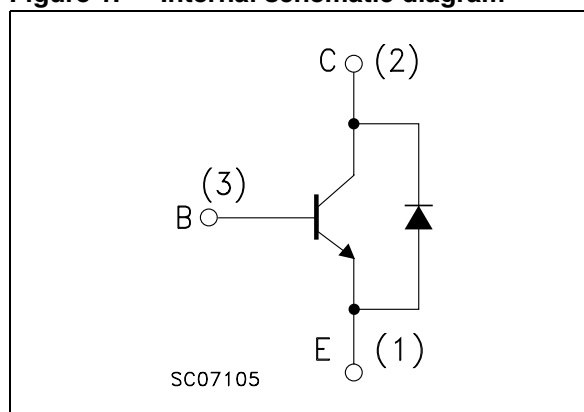
The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The STL series is designed for use in compact fluorescent lamps.



**Figure 1. Internal schematic diagram**



**Table 1. Device summary**

Order codes	Marking <sup>(1)</sup>	Package	Packaging
STL73D	L73DL	TO-92	Bag
	L73DH		
STL73D-AP	L73DL	TO-92	Ammopack
	L73DH		

1. The product is classified in DC current gain group L and group H, see [Table 5: hFE classification](#). STMicroelectronics reserves the right to ship from any group according to production availability.

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-emitter voltage ( $V_{BE} = 0$ )	700	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	400	V
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ , $I_B = 0.5$ A, $t_P < 10$ $\mu$ s)	$V_{(BR)EBO}$	V
$I_C$	Collector current	1.5	A
$I_{CM}$	Collector peak current ( $t_P < 5$ ms)	3	A
$I_B$	Base current	0.5	A
$I_{BM}$	Base peak current ( $t_P < 5$ ms)	1.5	A
$P_{TOT}$	Total dissipation at $T_C = 25$ °C	1.5	W
$T_{STG}$	Storage temperature	-65 to 150	°C
$T_J$	Max. operating junction temperature	150	°C

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJC}$	Thermal resistance junction-case max	83	°C/W

## 2 Electrical characteristics

$T_{\text{case}} = 25\text{ °C}$  unless otherwise specified.

**Table 4. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CEV}}$	Collector cut-off current ( $V_{\text{BE}} = -1.5\text{ V}$ )	$V_{\text{CE}} = 700\text{ V}$ $V_{\text{CE}} = 700\text{ V}$ $T_{\text{C}} = 125\text{ °C}$			1 5	mA mA
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ( $I_{\text{C}} = 0$ )	$I_{\text{E}} = 10\text{ mA}$	9		18	V
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ( $I_{\text{B}} = 0$ )	$I_{\text{C}} = 10\text{ mA}$	400			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 0.3\text{ A}$ $I_{\text{B}} = 60\text{ mA}$ $I_{\text{C}} = 0.6\text{ A}$ $I_{\text{B}} = 120\text{ mA}$ $I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 250\text{ mA}$		0.15 0.25 0.4	0.4 0.6 1	V V V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 0.6\text{ A}$ $I_{\text{B}} = 120\text{ mA}$		0.95	1.1	V
$h_{\text{FE}}$	DC current gain	$I_{\text{C}} = 0.6\text{ A}$ $V_{\text{CE}} = 3\text{ V}$ $I_{\text{C}} = 1.2\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	10 4		21 10	
$t_{\text{r}}$ $t_{\text{s}}$ $t_{\text{f}}$	Resistive load Rise time Storage time Fall time	$V_{\text{CC}} = 125\text{ V}$ $I_{\text{C}} = 1\text{ A}$ $I_{\text{B(on)}} = -I_{\text{B(off)}} = 200\text{ mA}$ $T_{\text{P}} = 25\text{ }\mu\text{s}$			1 4 0.7	$\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
$t_{\text{s}}$	Inductive load Storage time	$I_{\text{C}} = 0.3\text{ A}$ $V_{\text{Clamp}} = 300\text{ V}$ $I_{\text{B(on)}} = -I_{\text{B(off)}} = 60\text{ mA}$ $L = 3\text{ mH}$		0.3		$\mu\text{s}$
$V_{\text{F}}$	Diode forward voltage	$I_{\text{F}} = 0.5\text{ A}$			1.5	V

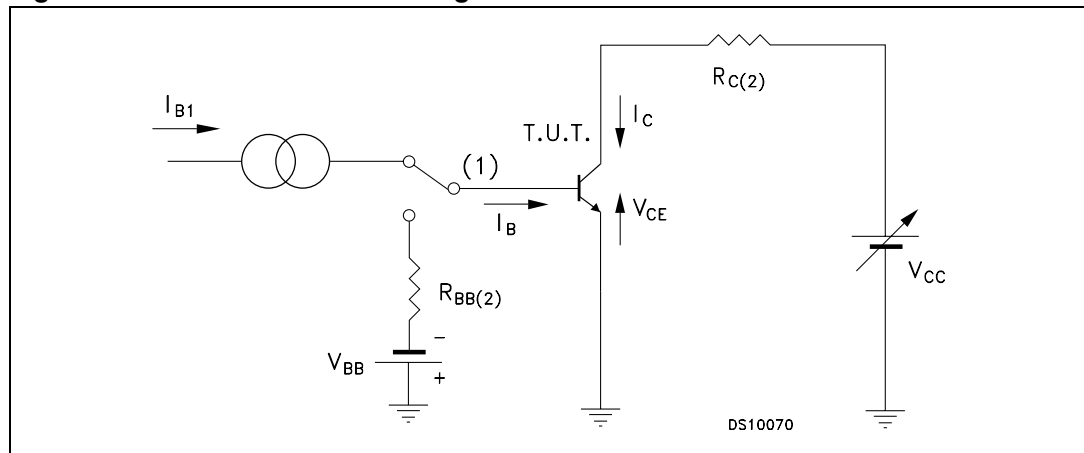
1. Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$

**Table 5.  $h_{\text{FE}}$  classification**

Symbol	Parameter	Group	Value		
			Min.	Max.	Unit
$h_{\text{FE}}$	DC current gain $V_{\text{CE}} = 3\text{ V}$ , $I_{\text{C}} = 0.6\text{ A}$	L	10	16	
		H	15	21	

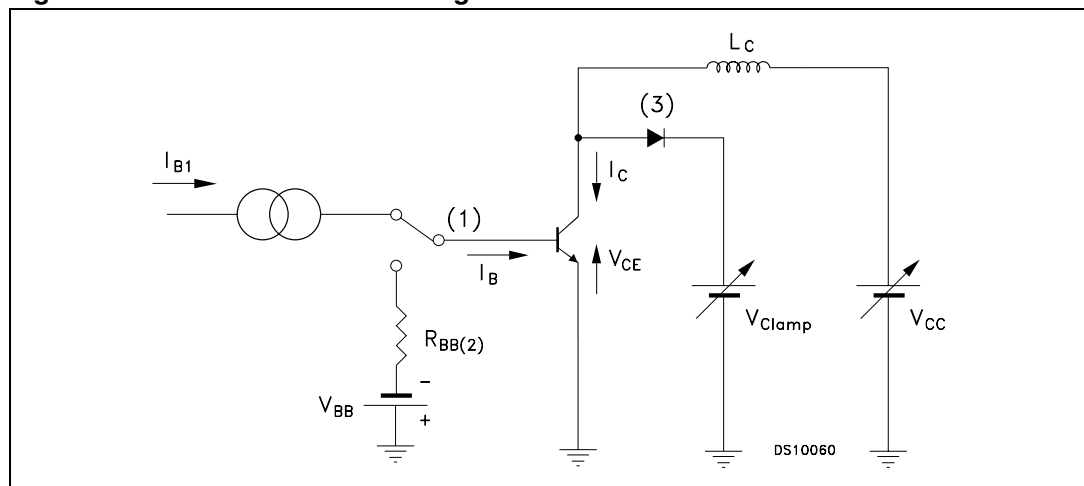
## 2.1 Test circuits

**Figure 2. Resistive load switching test circuit**



1. Fast electronic switch
2. Non-inductive resistor

**Figure 3. Inductive load switching test circuit**



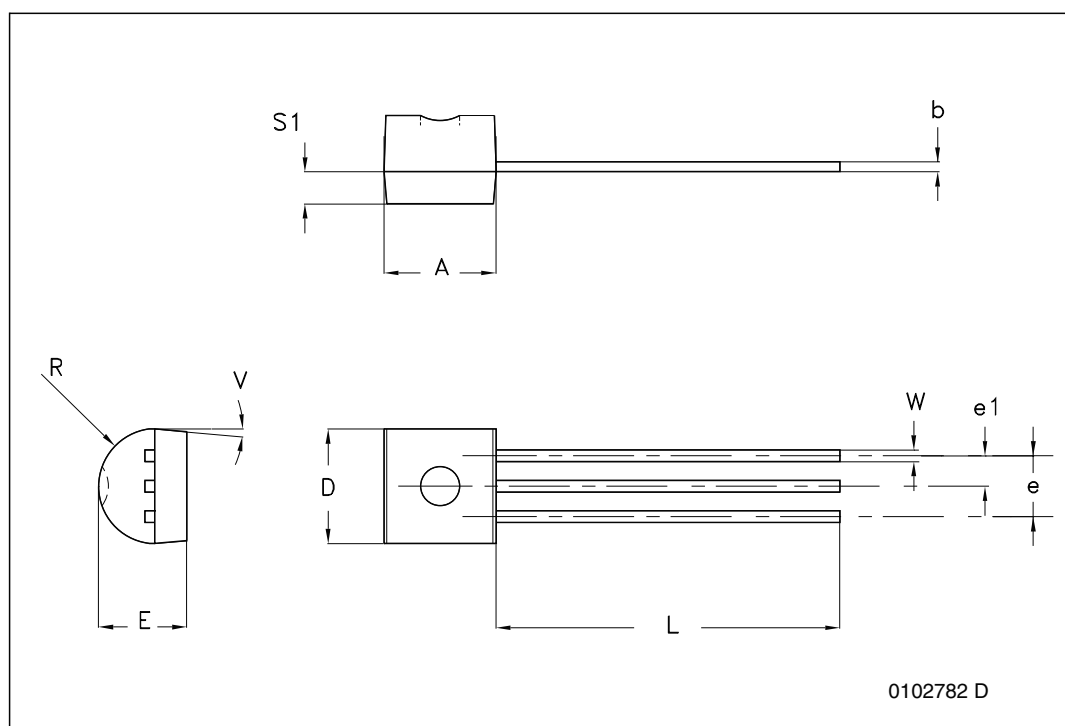
1. Fast electronic switch
2. Non-inductive resistor
3. Fast recovery rectifier

### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

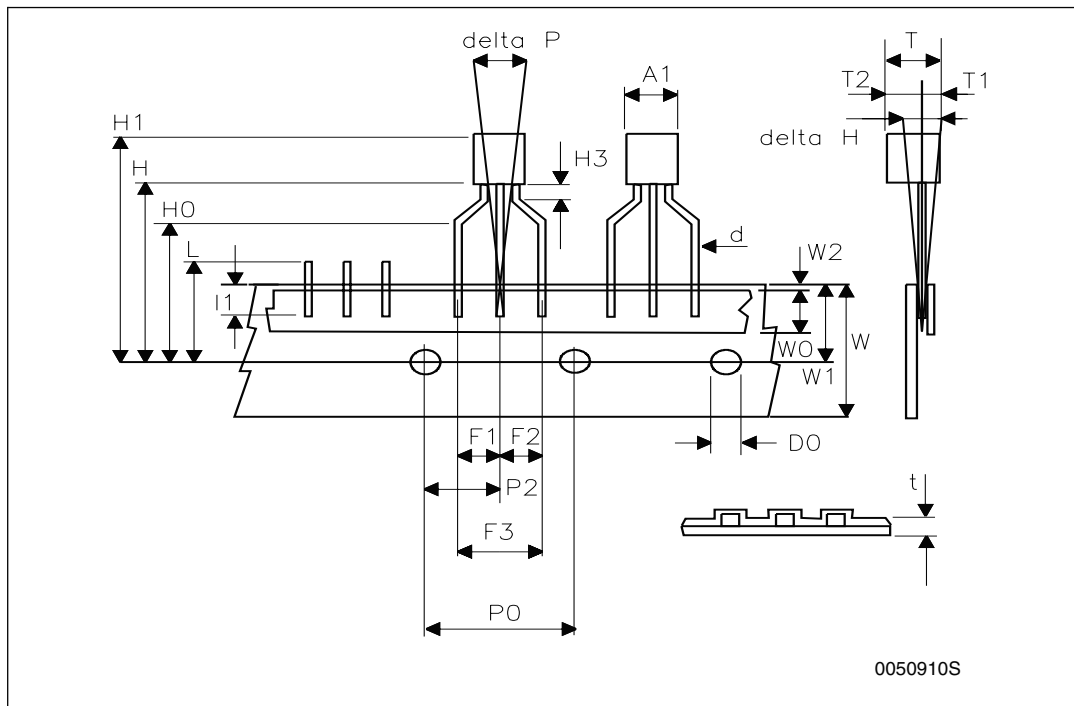
**TO-92 bulk shipment mechanical data**

Dim.	mm.		
	Min.	Typ.	Max.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	



**TO-92 ammpack shipment (suffix"-AP") mechanical data**

Dim.	mm.		
	Min.	Typ.	Max.
A1			4.80
T			3.80
T1			1.60
T2			2.30
d			0.48
P0	12.50	12.70	12.90
P2	5.65	6.35	7.05
F1,F2	2.44	2.54	2.94
F3	4.98	5.08	5.48
delta H	-2.00		2.00
W	17.50	18.00	19.00
W0	5.70	6.00	6.30
W1	8.50	9.00	9.25
W2			0.50
H	18.50		20.50
H3	0.5	1	1.5
H0	15.50	16.00	16.50
H1			25.00
D0	3.80	4.00	4.20
t			0.90
L			11.00
I1	3.00		
delta P	-1.00		1.00



## 4 Revision history

**Table 6. Document revision history**

Date	Revision	Changes
12-Nov-2008	1	Initial release.
25-Nov-2009	2	Added order code STL73D-AP <a href="#">Table 1 on page 1</a> .



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